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Form PTO 1449	<i>\$</i> /	U.S. DEPARTMENT	OF COMMERCE	ATTY DOCKET NO.		SERIAL I	VO .			
PATENT AND TRADEMARK OFFICE			293774US0PCT	10/586,397						
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				FILING DATE		GROUP				
				July 17, 2006						
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Examiner	/C	. Melissa Koslow/			Date Con	sidered	09/05	/2008		
*Examiner: In	itial if re	eference is considered,	whether or not	citation is in conformance with MPEP 60	9; Draw lir	ne through	citation	if not in		